Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	3756711	substrate wafer semiconductor mask photomask (photo adj mask)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2007/08/01 11:39
L2	483118	1 same (inspect\$ detect\$ defect)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/01 11:44
L3	2086184	sensiti\$7 major killer	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/01 11:45
L4	42760	2 same 3	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/01 11:42
L5	64599	1 near (inspect\$ detect\$ defect)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/01 11:44
L6	3912	5 same (sensiti\$7 major killer)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/01 11:53
L7	181	"382"/\$.ccls. and 6	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/01 11:53
L8	626	"356"/\$.ccls. and 6	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/01 11:53

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L9	85	"348"/\$.ccls. and 6	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/01 11:56
L10	855	gradation near difference	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/01 11:57
L11	4	6 and 10	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/01 11:57
L12	1	(sensiti\$6 and semiconductor and surface and predetermin\$4 and threshold and function and arithmetic and parameter and defect).clm.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/01 11:59
L13	421	(sensiti\$6 and semiconductor and surface and predetermin\$4 and threshold and function and arithmetic and parameter and defect)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/01 12:00
L14	1	(sensiti\$6 and semiconductor and surface and predetermin\$4 and threshold and function and arithmetic and parameter and defect).clm.	US-PGPUB	OR	ON	2007/08/01 12:00
L15	16	"382"/\$.ccls. and (sensiti\$6 and semiconductor and surface and predetermin\$4 and threshold and function and arithmetic and parameter and defect)	US-PGPUB	OR	ON	2007/08/01 12:01
L16	1	"382"/\$.ccls. and (sensiti\$6 and semiconductor and surface and predetermin\$4 and threshold and function and arithmetic and parameter and defect).clm.	US-PGPUB	OR	ON	2007/08/01 12:01
L17	0	"348"/\$.ccls. and (sensiti\$6 and semiconductor and surface and predetermin\$4 and threshold and function and arithmetic and parameter and defect).clm.	US-PGPUB	OR	ON	2007/08/01 12:01

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L18	0	"356"/\$.ccls. and (sensiti\$6 and semiconductor and surface and predetermin\$4 and threshold and function and arithmetic and parameter and defect).clm.	US-PGPUB	OR	ON	2007/08/01 12:01
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Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L14	1	(sensiti\$6 and semiconductor and surface and predetermin\$4 and threshold and function and arithmetic and parameter and defect).clm.	US-PGPUB	OR	ON	2007/08/01 12:00
L15	16	"382"/\$.ccls. and (sensiti\$6 and semiconductor and surface and predetermin\$4 and threshold and function and arithmetic and parameter and defect)	US-PGPÜB	OR	ON	2007/08/01 12:01
L16	1	"382"/\$.ccls. and (sensiti\$6 and semiconductor and surface and predetermin\$4 and threshold and function and arithmetic and parameter and defect).clm.	US-PGPUB	OR	ON	2007/08/01 12:01
L17	0	"348"/\$.ccls. and (sensiti\$6 and semiconductor and surface and predetermin\$4 and threshold and function and arithmetic and parameter and defect).clm.	US-PGPUB	OR	ON	2007/08/01 12:01
L18	0	"356"/\$.ccls. and (sensiti\$6 and semiconductor and surface and predetermin\$4 and threshold and function and arithmetic and parameter and defect).clm.	US-PGPUB	OR	ON	2007/08/01 12:01

INTERFERENCE TEXT SEARCH